

SPP02N60S5HKSA1

SPP02N60S5HKSA1 Information

www.heiseper.com	 SPP02N60S5HKSA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 600V 1.8A TO-220 TO-220-3 For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SPP02N60S5HKSA1 Specifications

Manufacturer Part Number	SPP02N60S5HKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	CoolMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	1.8A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5.5V @ 80µA
Gate Charge (Qg) (Max) @ Vgs	9.5nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	240pF @ 25V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	25W (Tc)
Rds On (Max) @ Id, Vgs	3 Ohm @ 1.1A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO220-3-1
Package / Case	TO-220-3
	Report errors?

SPP02N60S5HKSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SPP02N60S5HKSA1 Payment Methods





If you have any question about SPP02N60S5HKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com